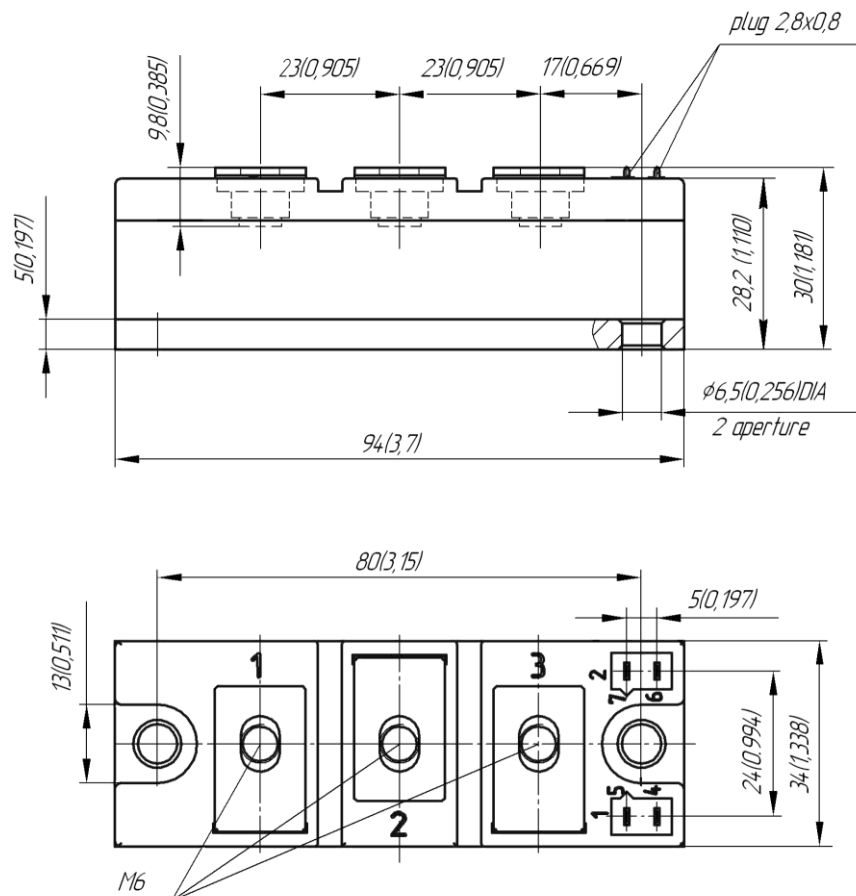
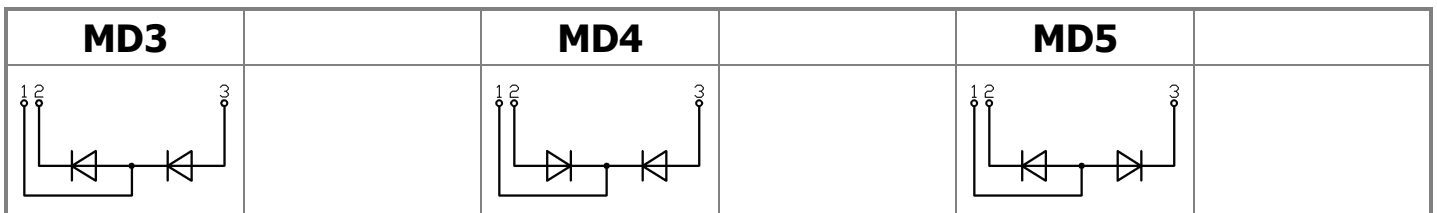




**Double Diode Module
For Phase Control
MDx-175-28-F**

Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

Average forward current		I_{FAV}	175 A
Repetitive peak reverse voltage		V_{RRM}	2400 ÷ 2800 V
V_{RRM}, V	2400	2600	2800
Voltage code	24	26	28
$T_j, ^\circ C$	- 40 ÷ 150		



All dimensions in millimeters (inches)


MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	175	$T_c=100\text{ }^\circ\text{C};$ 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	275		
I_{FSM}	Surge forward current	kA	6.0 7.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$	180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V};$
			7.0 8.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$	180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V};$
I^2t	Safety factor	$A^2s\cdot 10^3$	180 245	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$	180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V};$
			200 265	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ\text{C}$	180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V};$
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	2400÷2800	$T_{j\min}<T_j<T_{j\max};$ 180° half-sine wave; 50 Hz;	
V_{RSM}	Non-repetitive peak reverse voltages	V	2500÷2900	$T_{j\min}<T_j<T_{j\max};$ 180° half-sine wave; 50 Hz; single pulse;	
V_R	Reverse continuous voltages	V	$0.75\cdot V_{RRM}$	$T_j=T_{j\max};$	
THERMAL					
T_{stg}	Storage temperature	$^\circ\text{C}$	- 40 ÷ 125		
T_j	Operating junction temperature	$^\circ\text{C}$	- 40 ÷ 150		
MECHANICAL					
a	Acceleration under vibration	m/s^2	50		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V_{FM}	Peak forward voltage, max	V	1.50	$T_j=25\text{ }^\circ\text{C}; I_{FM}=500\text{ A}$	
$V_{F(TO)}$	Forward threshold voltage, max	V	0.85	$T_j=T_{j\max};$ $0.5\pi I_{FAV}<I_T<1.5\pi I_{FAV}$	
r_T	Forward slope resistance, max	$m\Omega$	1.500		
BLOCKING					
I_{RRM}	Repetitive peak reverse current, max	mA	35	$T_j=T_{j\max}; V_R=V_{RRM}$	
SWITCHING					
Q_{rr}	Total recovered charge, max	μC	1050	$T_j=T_{j\max}; I_{FM}=200\text{ A};$ $di_R/dt=-10\text{ A}/\mu\text{s};$ $V_R=100\text{ V};$	
t_{rr}	Reverse recovery time, max	μs	21		
I_{rrM}	Peak reverse recovery current, max	A	100		
THERMAL					
R_{thjc}	Thermal resistance, junction to case			180° half-sine wave, 50 Hz DC	
	per module	$^\circ\text{C}/\text{W}$	0.0950		
	per arm	$^\circ\text{C}/\text{W}$	0.1900		
	per module	$^\circ\text{C}/\text{W}$	0.0900		
	per arm	$^\circ\text{C}/\text{W}$	0.1800		
R_{thch}	Thermal resistance, case to heatsink				
	per module	$^\circ\text{C}/\text{W}$	0.0300		
	per arm	$^\circ\text{C}/\text{W}$	0.0600		

INSULATION					
V _{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS	t=1 min
			3.60		t=1 sec
MECHANICAL					
M ₁	Mounting torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
M ₂	Terminal connection torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
w	Weight	g	320		

PART NUMBERING GUIDE						NOTES					
MD	3	-	175	-	28	-	F	-	N		¹⁾ The screws must be lubricated
1	2		3		4		5		6		
1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.F) 6. Ambient Conditions: N – Normal											
		UL certified file-No. E255404									

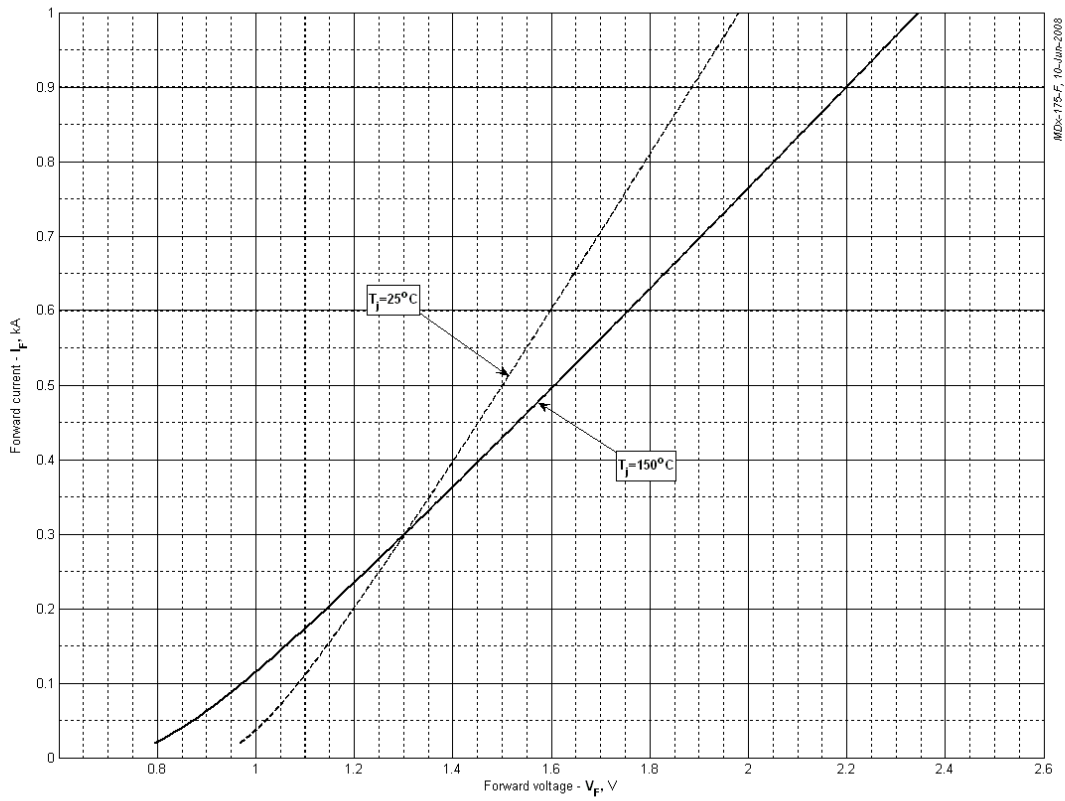


Fig 1 – On-state characteristics of Limit device

Analytical function for On-state characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\text{max}}$
A	0.905049	0.703945
B	0.944830	1.455245
C	-0.356768	-0.506419
D	0.379050	0.538047

On-state characteristic model (see Fig. 1)

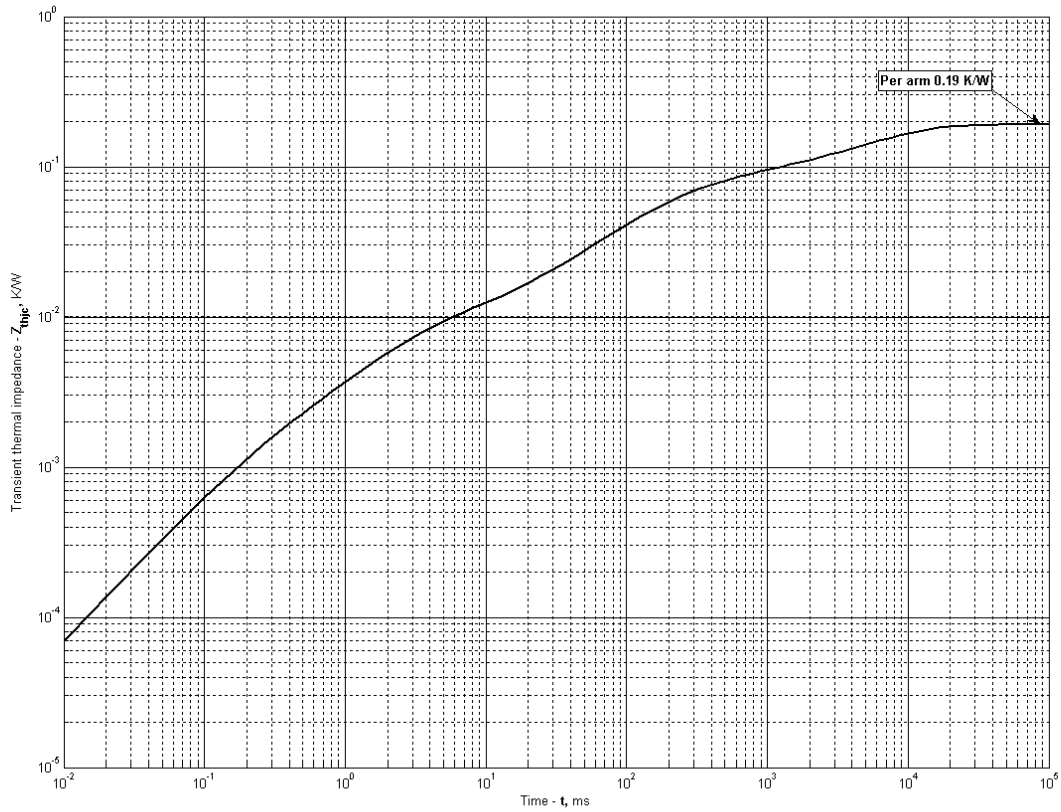


Fig 2 – Transient thermal impedance

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t .

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

i	1	2	3	4	5	6
R_i K/W	0.0007824	0.007029	0.01292	0.04452	0.0191	0.1056
τ_{ij} S	0.0002166	0.002381	0.06714	0.1793	0.602	6.635

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

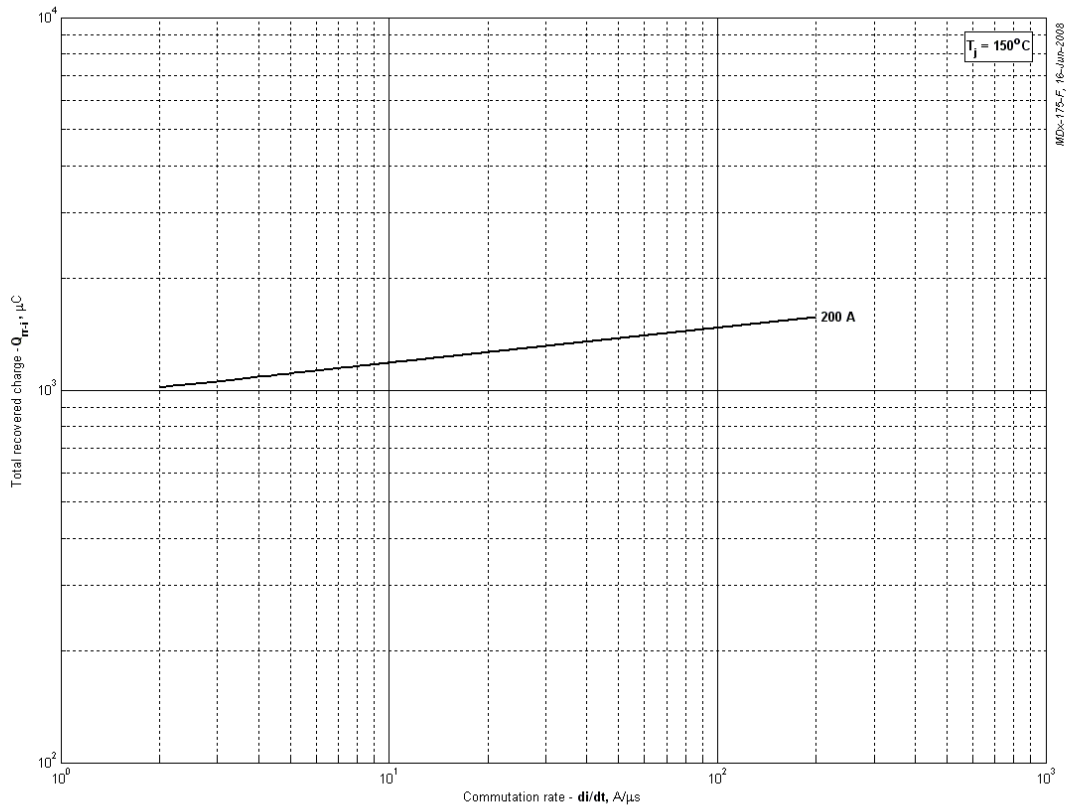


Fig 3 – Total recovered charge, Q_{rr-i} (integral)

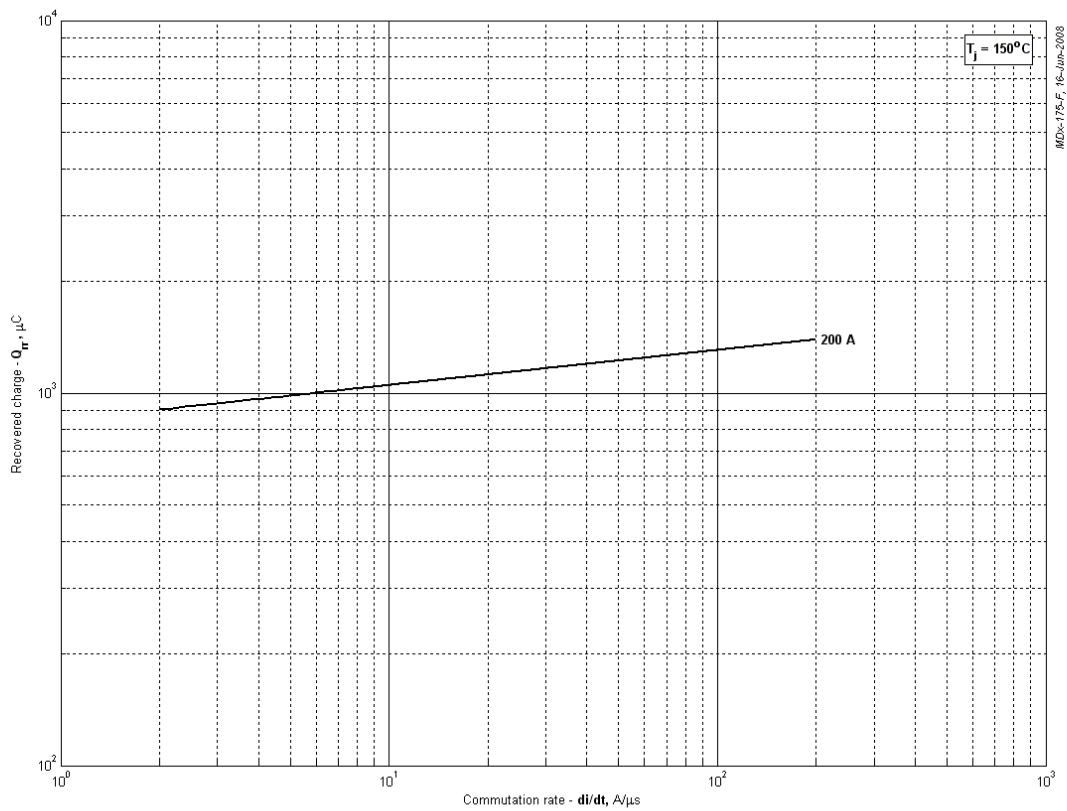


Fig 4 - Recovered charge, Q_{rr} (linear)

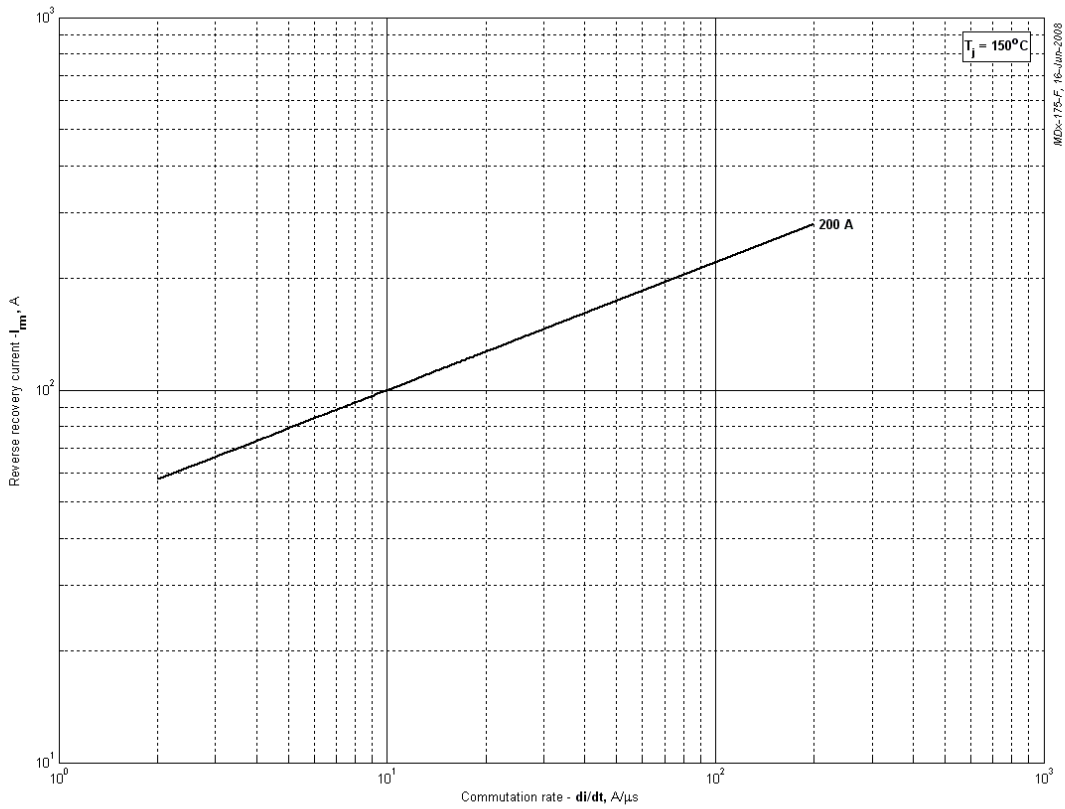


Fig 5 – Peak reverse recovery current, I_{rm}

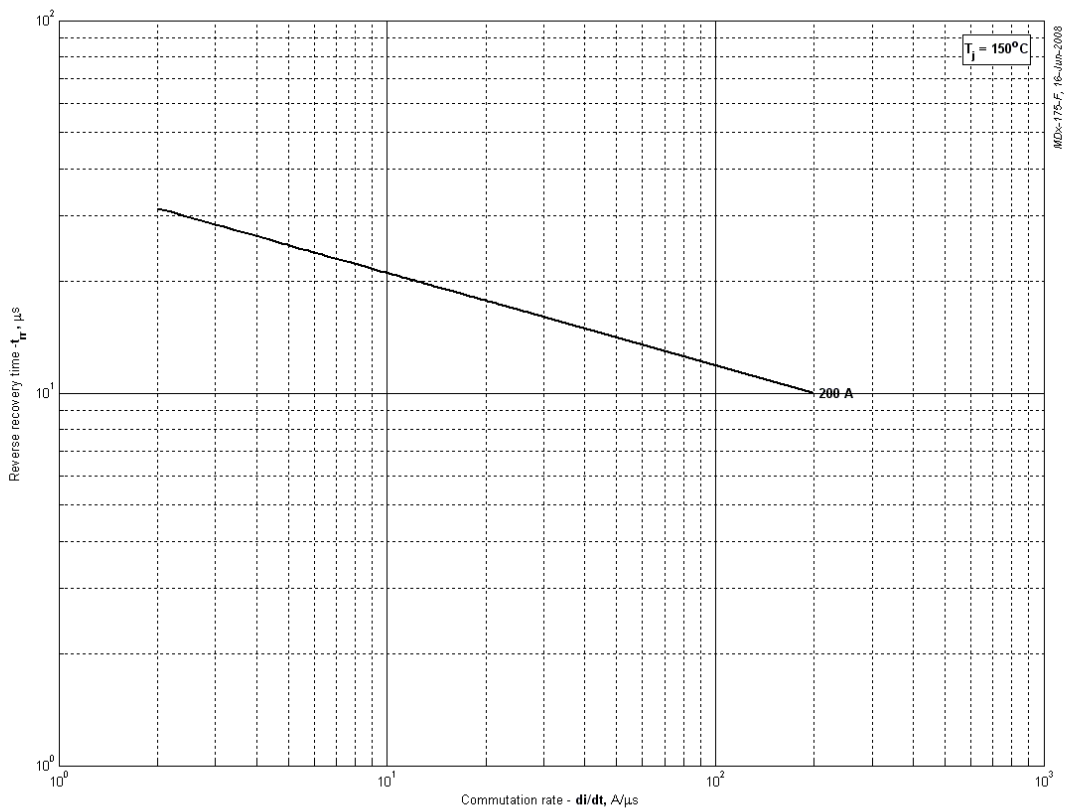


Fig 6 – Maximum recovery time, t_{tr} (linear)

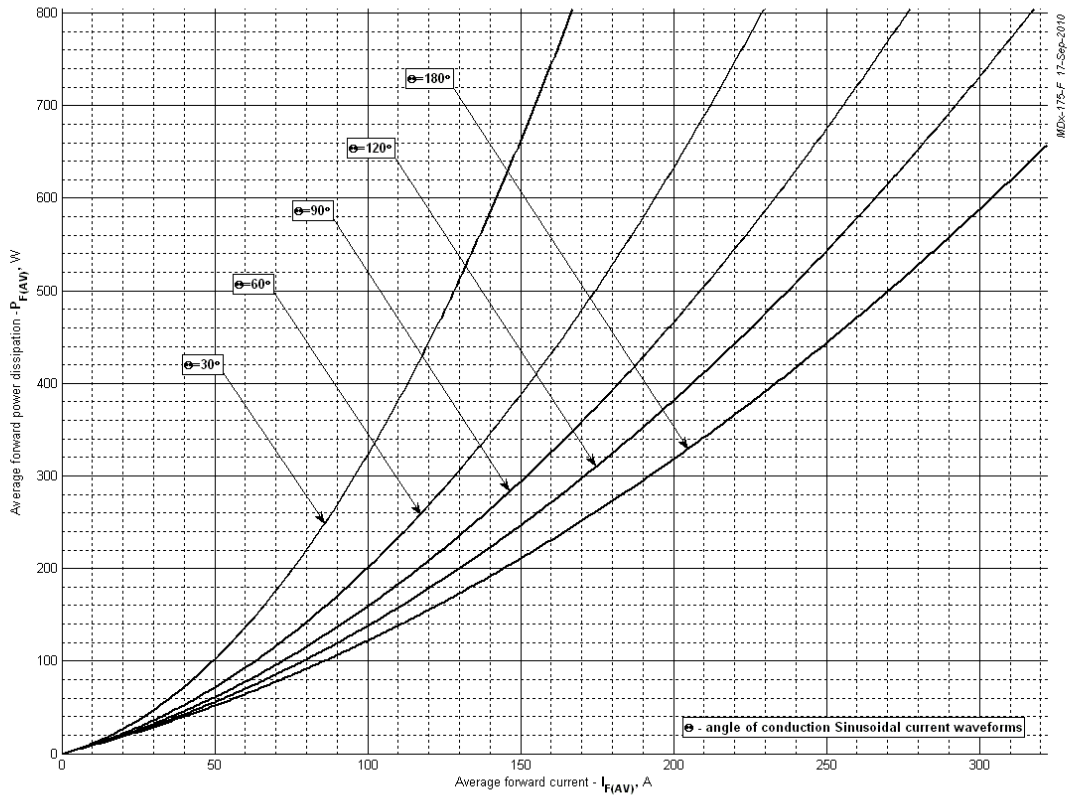


Fig 7 – On-state power loss (sinusoidal current waveforms)

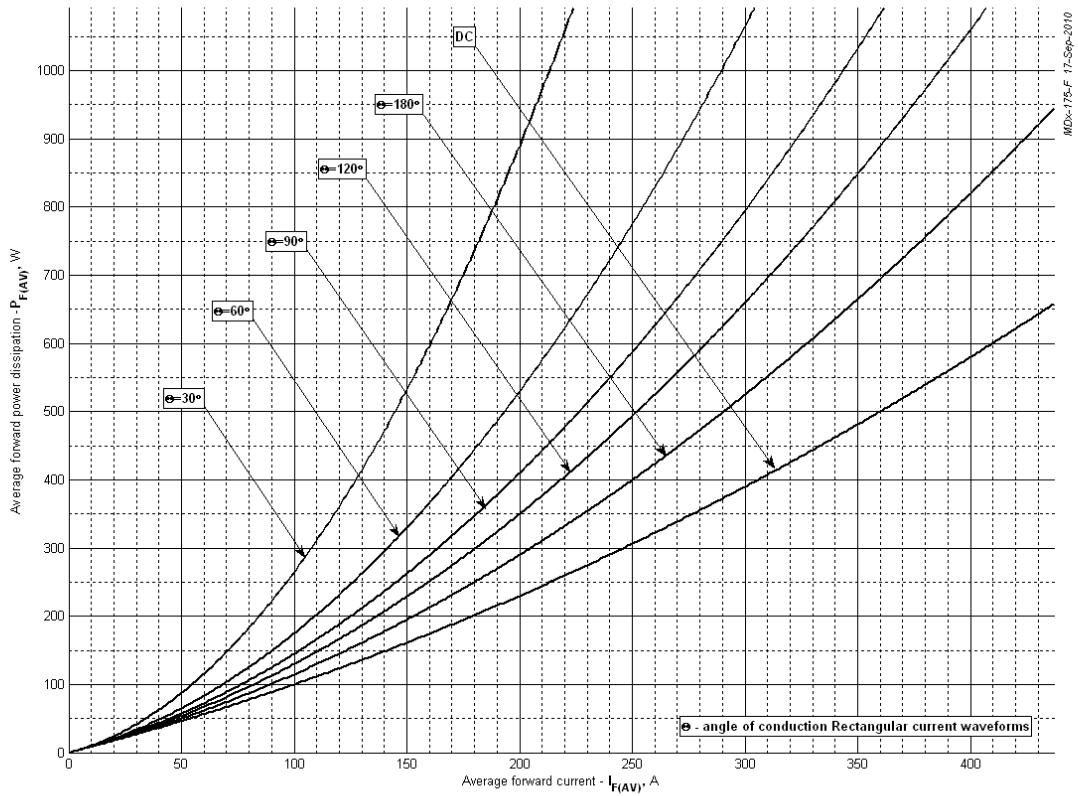


Fig 8 – On-state power loss (rectangular current waveforms)

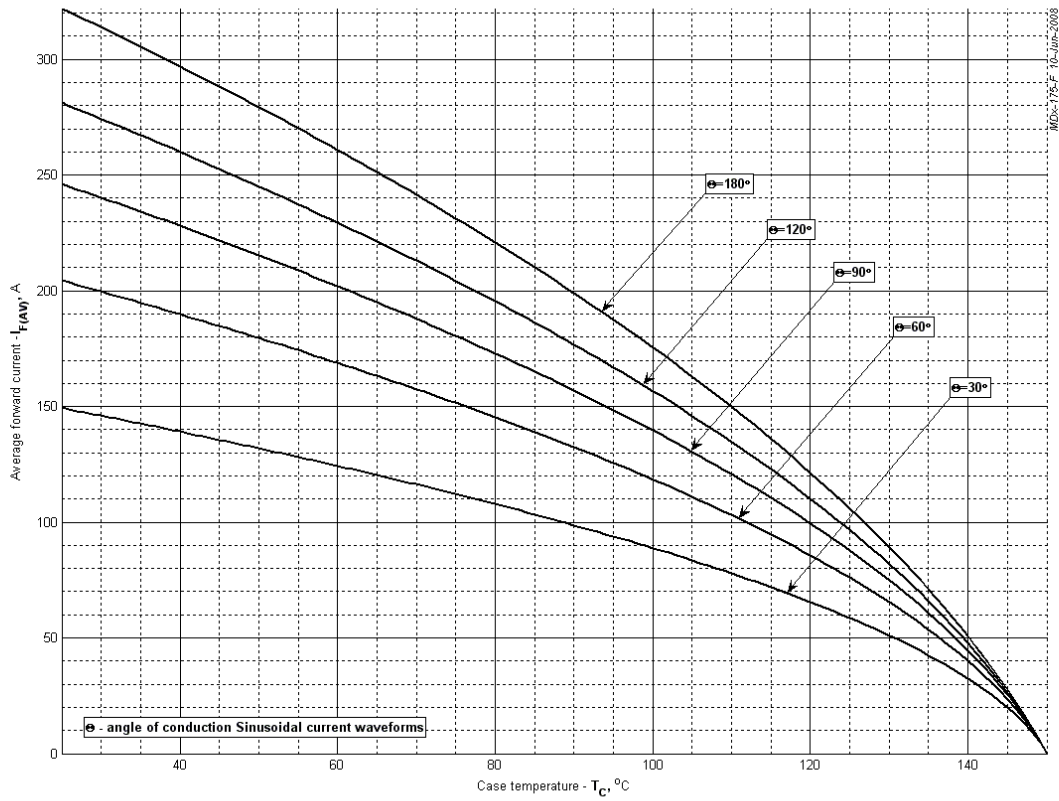


Fig 9 – Maximum case temperature DSC (sinusoidal current waveforms)

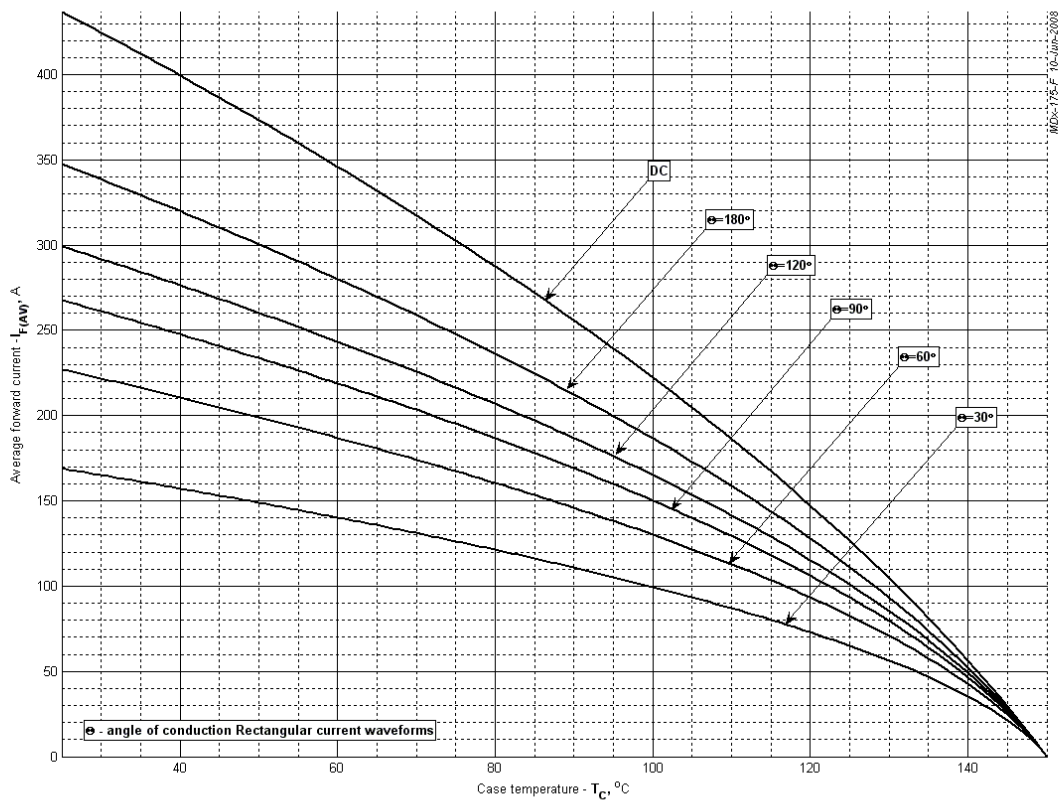


Fig 10 – Maximum case temperature DSC (rectangular current waveforms)

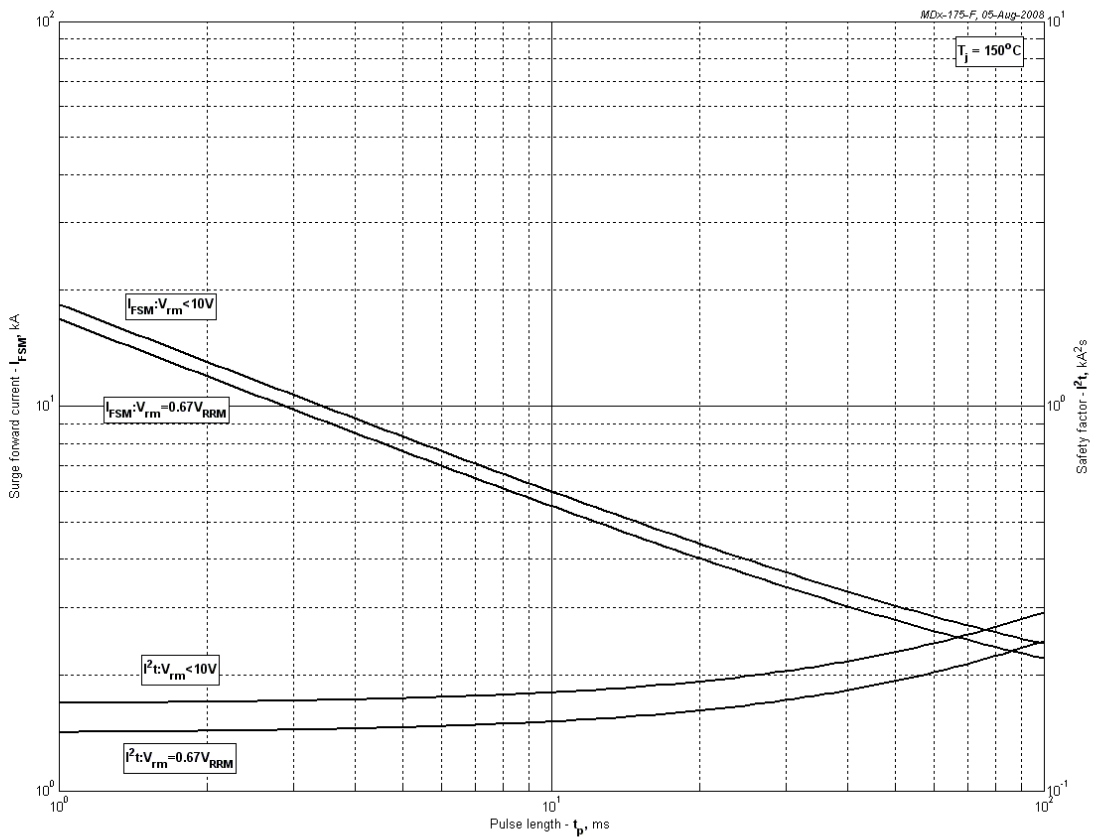


Fig 11 – Maximum surge and I²t ratings

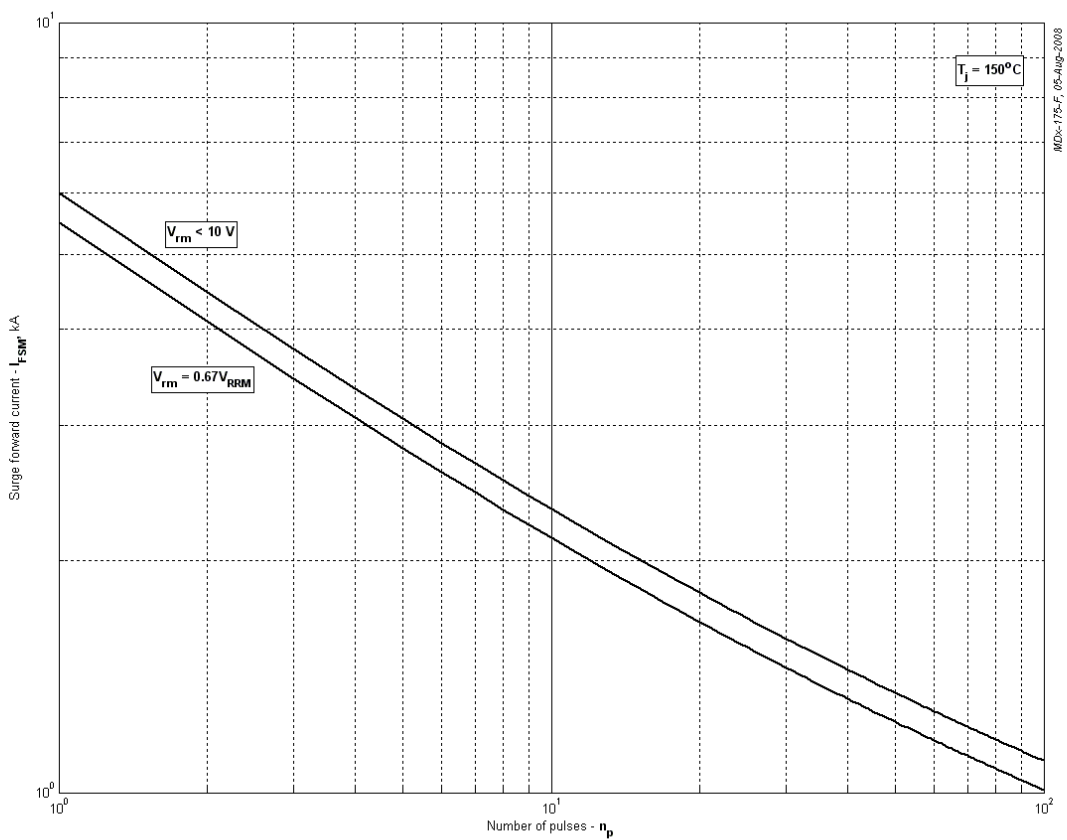


Fig 12 – Maximum surge ratings